

MR26V01G53L

64M–Word × 16–Bit or 128M–Word × 8–Bit Page Mode P2ROM

FEATURES

- · 64M-word \times 16-bit / 128M-word \times 8-bit electrically switchable configuration
- Page size of 8-word x 16-Bit or 16-word x 8-Bit
- 3.0 V to 3.6 V power supply
- Random Access time 105 ns MAX
- Page Access time 35 ns MAX
- Operating current 100 mA MAX
- Standby current 10 mA MAX
- Input/Output TTL compatible
- · Three-state output

PACKAGES

• MR26V01G53L-xxxMB 70-pin plastic SSOP (P-SSOP70-500-0.80-EK-MC)

P2ROM ADVANCED TECHNOLOGY

P2ROM stands for Production Programmed ROM. This exclusive LAPIS Semiconductor technology utilizes factory test equipment for programming the customers code into the P2ROM prior to final production testing. Advancements in this technology allows production costs to be equivalent to MASKROM and has many advantages and added benefits over the other non-volatile technologies, which include the following;

• Short lead time, since the P2ROM is programmed at the final stage of the production process, a large P2ROM inventory "bank system" of un-programmed packaged products are maintained to provide an aggressive lead-time and minimize liability as a custom product.

• **No mask charge**, since P2ROMs do not utilize a custom mask for storing customer code, no mask charges apply.

• No additional programming charge, unlike Flash and OTP that require additional programming and handling costs, the P2ROM already has the code loaded at the factory with minimal effect on the production throughput. The cost is included in the unit price.

• Custom Marking is available at no additional charge

| PIN CONFIG | URATION (1 | OP VIEW) |
|--|------------|--|
| A11 [1 A10 [2 A9 [3] A8 [2 A8 [4] A7 [4] A6 [6] A5 [7] A6 [6] A3 [1 A1 [1] A2 [1] A1 [1] A2 [1] A2 [1] A2 [1] NC [1] NC [1] NC [1] NC [1] NC [1] NC [1] NC [1] NC [2] NC [| | 70 CE# 69 A12 68 A13 67 A14 66 A15 65 Vcc 64 A16 63 A17 62 A18 61 A19 60 A20 59 A21 58 NC 55 NC 54 NC 55 NC 54 NC 55 NC 54 NC 55 NC 54 NC 55 NC 56 NC 57 NC 58 NC 59 NC 54 NC 55 NC 56 NC 57 NC 58 NC 59 NC 44 D15/A-1 43 D7 44 D13 39 D5 38 <td< td=""></td<> |
| | | |

BLOCK DIAGRAM



In 8-bit output mode, these pins are placed in a high-Z state and pin D15 functions as the A-1 address pin.

PIN DESCRIPTIONS

| Pin name | Functions |
|-----------------|-----------------------------|
| D15 / A–1 | Data output / Address input |
| A0 to A24 | Address inputs |
| D0 to D14 | Data outputs |
| CE# | Chip enable input |
| OE#1 OE#2 | Output enable input |
| BYTE# | Word / Byte select input |
| Vcc | Power supply voltage |
| V _{SS} | Ground |
| NC | No connect |
| | |

FUNCTION TABLE

| | | | | | | | (Vcc=3) | .0V~3.6V) | |
|--------------------------------------|-----------------|-----|------|------|-------|--------------------------|--------------------------|-----------|--|
| Mode | Address | CE# | OE#1 | OE#2 | BYTE# | D0 to D7 | D8 to D14 | D15/A–1 | |
| Road (16 Pit) | 0000000-1FFFFFF | | L | Н | ц | D _{OUT} (MSB=0) | | | |
| Read (16-Bit) | 2000000-3FFFFFF | L | Н | L | п | [| D _{OUT} (MSB=1) | | |
| Read (8-Bit) 000000-3F 4000000-7F | 0000000-3FFFFFF | L | L | Н | L | D _{OUT} | Hi–Z | 1/Ц | |
| | 4000000-7FFFFFF | | Н | L | | | | L/Π | |
| Output dischlo | | | Ц | L Ц | Н | | | | |
| Output disable | * | L | п | п | L | | | * | |
| Standby | r. | ц | * | sk | Н | | ⊔; 7 | | |
| | * | Π | | * | L | | ΠΙ-Ζ | * | |

*: Don't Care (H or L)

ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Condition | Value | Unit |
|----------------------------------|--------|-----------------------------|------------------------------|------|
| Operating temperature under bias | Та | | 0 to 70 | °C |
| Storage temperature | Tstg | — | -55 to 125 | °C |
| Input voltage | VI | | –0.5 to V _{CC} +0.5 | V |
| Output voltage | Vo | Relative to V _{SS} | –0.5 to V _{CC} +0.5 | V |
| Power supply voltage | Vcc | | –0.5 to 5 | V |
| Power dissipation per package | PD | Ta = 25°C | 1.0 | W |
| Output short circuit current | los | — | 10 | mA |

RECOMMENDED OPERATING CONDITIONS

 $(Ta = 0 \text{ to } 70^{\circ}C)$

| Parameter | Symbol | Condition | Min. | Тур. | Max. | Unit |
|--------------------------------------|-----------------|-------------------------|--------|------|-----------------------|------|
| V _{CC} power supply voltage | V _{cc} | | 3.0 | — | 3.6 | V |
| Input "H" level | VIH | V_{CC} = 3.0 to 3.6 V | 2.2 | _ | V _{CC} +0.5* | V |
| Input "L" level | VIL | | -0.5** | — | 0.6 | V |

Voltage is relative to V_{SS}.

* : Vcc+1.5V(Max.) when pulse width of overshoot is less than 10ns.

** : -1.5V(Min.) when pulse width of undershoot is less than 10ns.

PIN CAPACITANCE

| | | | | $(V_{CC} = 3.3)$ | $V, Ta = 25^{\circ}C$ | <i>L</i> , f = 1 MHz) |
|-----------|------------------|-------------|------|------------------|-----------------------|-----------------------|
| Parameter | Symbol | Condition | Min. | Тур. | Max. | Unit |
| Input | C _{IN1} | | — | — | 15 | |
| BYTE# | C _{IN2} | $v_1 = 0 v$ | _ | — | 400 | pF |
| Output | C _{OUT} | $V_0 = 0 V$ | _ | _ | 15 | |

ELECTRICAL CHARACTERISTICS

DC Characteristics

| | | | (V ₀ | $_{\rm CC} = 3.0 \ {\rm V} \ {\rm t}$ | o 3.6 V, Ta | $= 0$ to 70° C) |
|---|-------------------|--|-----------------|---------------------------------------|---------------------------|--------------------------|
| Parameter | Symbol | Condition | Min. | Тур. | Max. | Unit |
| Input leakage current | ۱ _{LI} | $V_I = 0$ to V_{CC} | — | _ | 10 | μA |
| Output leakage current | I _{LO} | $V_{O} = 0$ to V_{CC} | — | _ | 10 | μA |
| V _{CC} power supply current | Iccsc | $CE\# = V_{CC}$ | _ | _ | 10 | mA |
| (Standby) | ICCST | $CE\# = V_{IH}$ | _ | _ | 10 | mA |
| V _{CC} power supply current (Read) | I _{CCA1} | $CE\# = V_{IL}, OE\# = V_{IH}$ f=5MHz | _ | — | 100 | mA |
| Input "H" level | VIH | — | 2.2 | _ | V _{CC} +0.5 * | V |
| Input "L" level | VIL | — | -0.5** | _ | 0.6 | V |
| Output "H" level | V _{OH} | I _{OH} = –1 mA | 2.4 | _ | | V |
| Output "L" level | V _{OL} | $I_{OL} = 2 \text{ mA}$ | _ | _ | 0.4 | V |

Voltage is relative to V_{SS}.

* : Vcc+1.5V(Max.) when pulse width of overshoot is less than 10ns.

** : -1.5V(Min.) when pulse width of undershoot is less than 10ns.

AC Characteristics

| | | | $(V_{CC} = 3.0)$ |) V to 3.6 V, Ta | $= 0$ to 70° C) |
|---------------------|------------------|--|------------------|------------------|--------------------------|
| Parameter | Symbol | Condition | Min. | Max. | Unit |
| Address cycle time | t _C | — | 105 | — | ns |
| Address access time | t _{ACC} | $CE\# = V_{IL}$ OE1# or OE2#= V_{IL} | — | 105 | ns |
| Page cycle time | t _{PC} | — | 35 | — | ns |
| Page access time | t _{PAC} | CE# = V _{IL} OE1# or OE2#= V _{IL} | — | 35 | ns |
| CE# access time | t _{CE} | OE1# or OE2#= V _{IL} | — | 105 | ns |
| OE# access time | t _{OE} | $CE\# = V_{IL}$ | — | 30 | ns |
| OE# delay time | t _{OES} | — | 0 | — | ns |
| Output disable time | t _{CHZ} | OE1# or OE2#= VIL | 0 | 20 | ns |
| Output disable time | t _{OHZ} | $CE\# = V_{IL}$ | 0 | 20 | ns |
| Output hold time | t _{OH} | CE# = V _{IL} OE1# or OE2#= V _{IL} | 0 | — | ns |

Measurement conditions

| Input signal level | 0 V/3 V |
|------------------------------|---------|
| Input timing reference level | 1/2Vcc |
| Output load | 50 pF |
| | |

Output timing reference level ------ 1/2Vcc

Output load



TIMING CHART (READ CYCLE)

Random Access Mode Read Cycle



Page Access Mode Read Cycle



PACKAGE DIMENSIONS



Notes for Mounting the Surface Mount Type Package

The surface mount type packages are very susceptible to heat in reflow mounting and humidity absorbed in storage.

Therefore, before you perform reflow mounting, contact ROHM's responsible sales person for the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).

REVISION HISTORY

| Document | | Page | | | |
|----------------------|---------------|---------------------|--------------------|--|--|
| No. | Date | Previous Edition | Current Edition | Description | |
| FEDR26V01G53L-02-01 | Jul. 29, 2005 | _ | _ | Final edition 1 | |
| FEDR26V01G53L-002-01 | Oct. 1, 2008 | _ | _ | Changed company logo and name to OKI SEMICONDUCTOR | |

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